



20 April 2020

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a small SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Low threshold voltage
- Extended temperature range T_i = 175 °C
- Very fast switching
- Trench MOSFET technology
- AEC-Q101 qualified

3. Applications

- Relay driver
- High-speed line driver
- High-side load switch
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

-							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-20	V
V _{GS}	gate-source voltage			-12	-	12	V
I _D	drain current	V _{GS} = -4.5 V; T _{amb} = 25 °C	[1]	-	-	-4.4	А
Static characte	eristics		·	·	·	·	
R _{DSon}	drain-source on-state resistance	V _{GS} = -4.5 V; I _D = -4.4 A; T _j = 25 °C		-	43	55	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².



5. Pinning information

Table 2	. Pinning info	rmation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	D	drain		D
2	D	drain		
3	G	gate		G_(Imp)
4	S	source	☐1 ☐2 ☐ 3 SC-74; TSOP6 (SOT457)	s
5	D	drain		017aaa094
6	D	drain		

6. Ordering information

Table 3. Ordering information

Type number Package					
	Name	Description	Version		
PMN48XPA2	SC-74; TSOP6	plastic, surface-mounted package (SC-74; TSOP6); 6 leads	SOT457		

7. Marking

Table 4. Marking codes

Type number	Marking code
PMN48XPA2	6E

8. Limiting values

Table 5. Limiting values

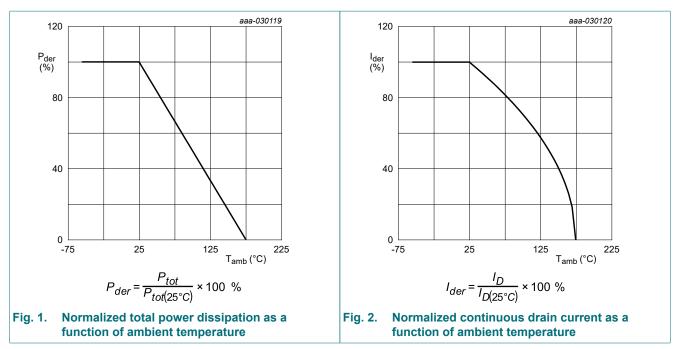
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-20	V
V _{GS}	gate-source voltage	-		-12	12	V
I _D	drain current	V _{GS} = -4.5 V; T _{amb} = 25 °C	[1]	-	-4.4	А
		V _{GS} = -4.5 V; T _{amb} = 100 °C	[1]	-	-2.8	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-18	А
P _{tot} to	total power dissipation	T _{amb} = 25 °C	[2]	-	660	mW
			[1]	-	1.7	W
		T _{sp} = 25 °C		-	7.5	W
Tj	junction temperature			-55	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C
Source-drain	n diode			I		
I _S	source current	T _{amb} = 25 °C	[1]	-	-1.7	А
ESD maximu	um rating					
V _{ESD}	electrostatic discharge voltage	НВМ	[3]	-	400	V
Avalanche r	uggedness			1		
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	T _{j(init)} = 25 °C; I _D = -1 A; DUT in avalanche (unclamped)		-	10	mJ
		1	1			

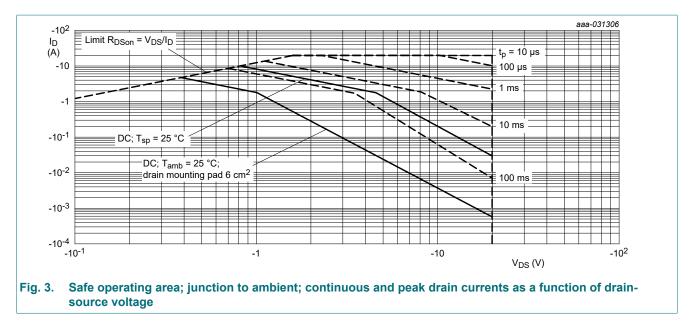
[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[3] Measured between all pins.



20 V, P-channel Trench MOSFET

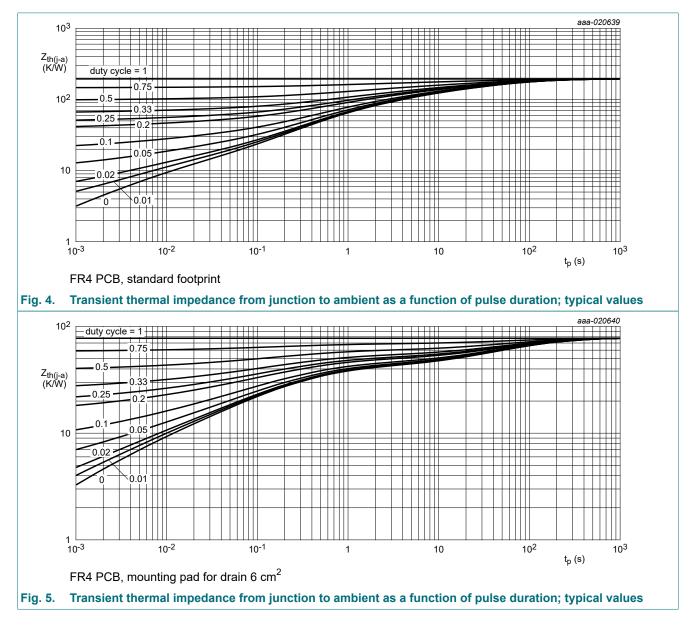


9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
ui()-a)	thermal resistance from	in free air	[1]	-	195	225	K/W
	junction to ambient		[2]	-	78	90	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	15	20	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

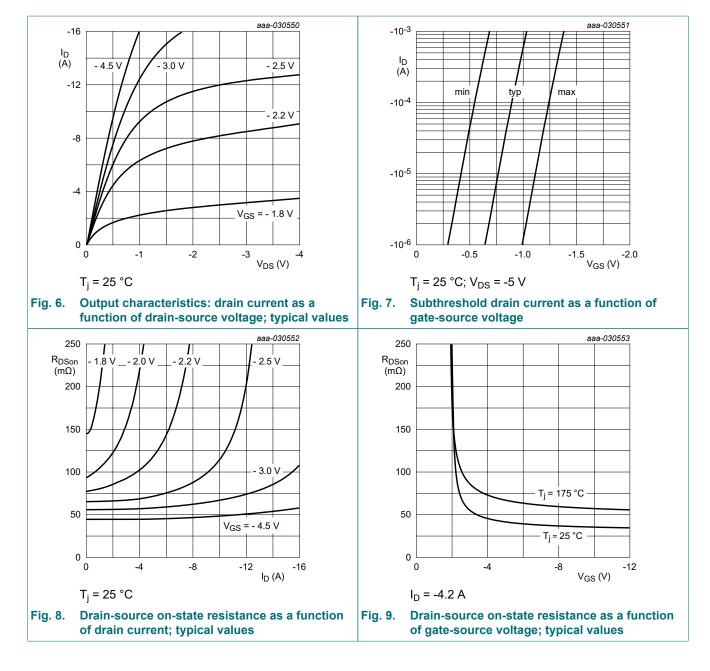
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm².



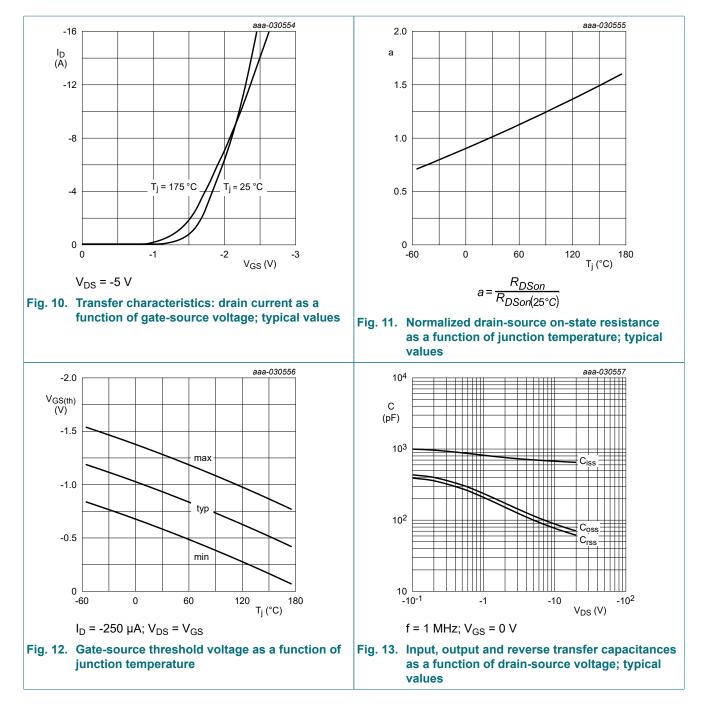
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	cteristics					
V _{(BR)DSS}	drain-source breakdown voltage	I _D = -250 μA; V _{GS} = 0 V; T _j = 25 °C	-20	-	-	V
V _{GSth}	gate-source threshold voltage	I _D = -250 μA; V _{DS} = V _{GS} ; T _j = 25 °C	-0.6	-0.95	-1.3	V
I _{DSS}	drain leakage current	V _{DS} = -20 V; V _{GS} = 0 V; T _j = 25 °C	-	-	-1	μA
I _{GSS} gate leakage current	gate leakage current	V _{GS} = -12 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-100	nA
		V _{GS} = 12 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state	V _{GS} = -8 V; I _D = -4.4 A; T _j = 25 °C	-	37	49	mΩ
	resistance	V _{GS} = -8 V; I _D = -4.4 A; T _j = 175 °C	-	59	78	mΩ
		V _{GS} = -4.5 V; I _D = -4.4 A; T _j = 25 °C	-	43	55	mΩ
		V _{GS} = -2.5 V; I _D = -2 A	-	65	90	mΩ
9 _{fs}	forward transconductance	V _{DS} = -10 V; I _D = -4.2 A; T _j = 25 °C	-	54	-	S
R _G	gate resistance	f = 1 MHz	-	7	-	Ω
Dynamic ch	aracteristics		I	I		
Q _{G(tot)}	total gate charge	V_{DS} = -10 V; I _D = -4.2 A; V _{GS} = -4.5 V;	-	7	10	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	1.3	-	nC
Q _{GD}	gate-drain charge	1	-	2.3	-	nC
C _{iss}	input capacitance	V _{DS} = -10 V; f = 1 MHz; V _{GS} = 0 V;	-	679	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	87	-	pF
C _{rss}	reverse transfer capacitance		-	75	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = -10 V; I _D = -4.2 A; V _{GS} = -4.5 V;	-	7	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	19	-	ns
t _{d(off)}	turn-off delay time		-	26	-	ns
t _f	fall time	1 – – – – – – – – – – – – – – – – – – –	-	13	-	ns
Source-drai	n diode	· · ·				
V _{SD}	source-drain voltage	I_{S} = -1.5 A; V_{GS} = 0 V; T_{j} = 25 °C	-	-0.8	-1.2	V
t _{rr}	reverse recovery time	I _S = -1.7 A; dI _S /dt = 100 A/μs;	-	10	-	ns
Q _r	recovered charge	V _{GS} = 0 V; V _{DS} = -10 V; T _j = 25 °C	-	2	-	nC

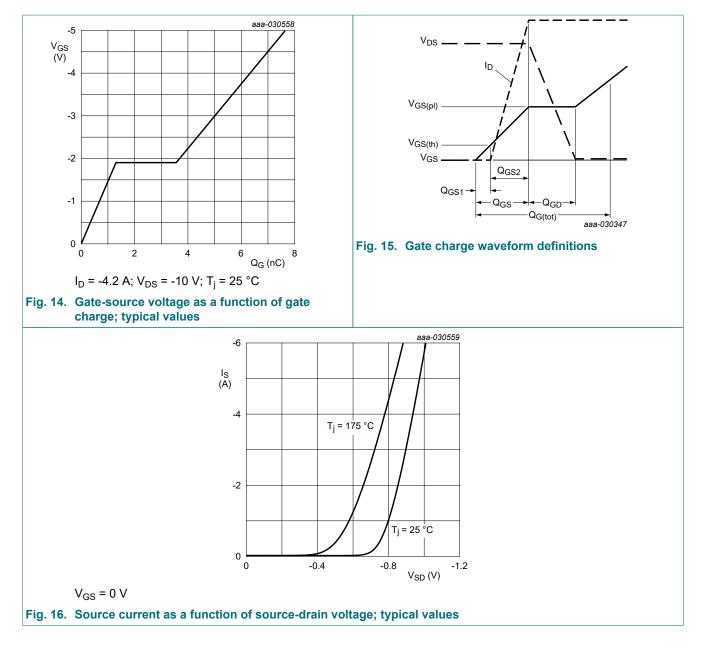
20 V, P-channel Trench MOSFET



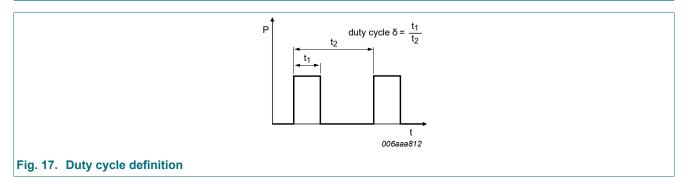
20 V, P-channel Trench MOSFET



20 V, P-channel Trench MOSFET



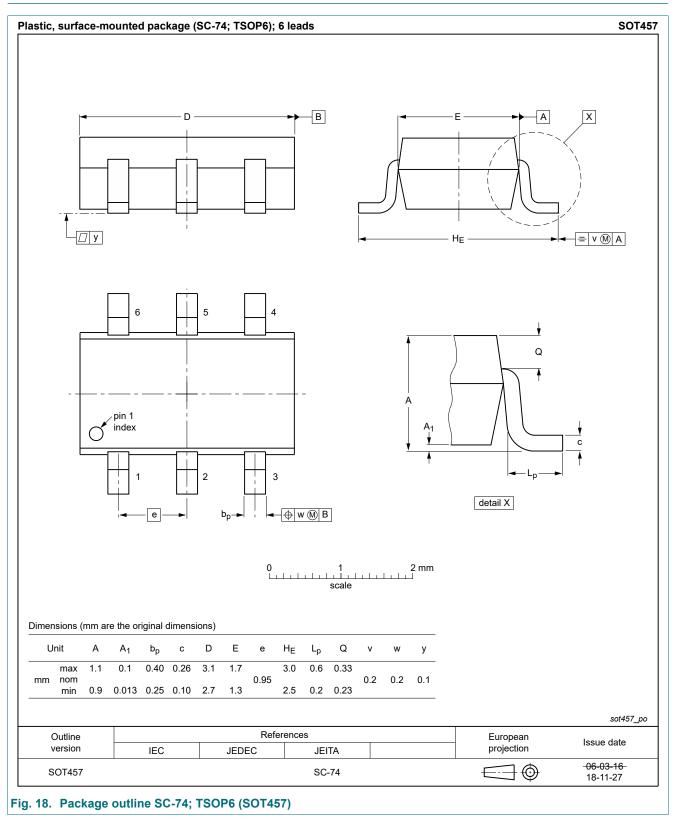
11. Test information



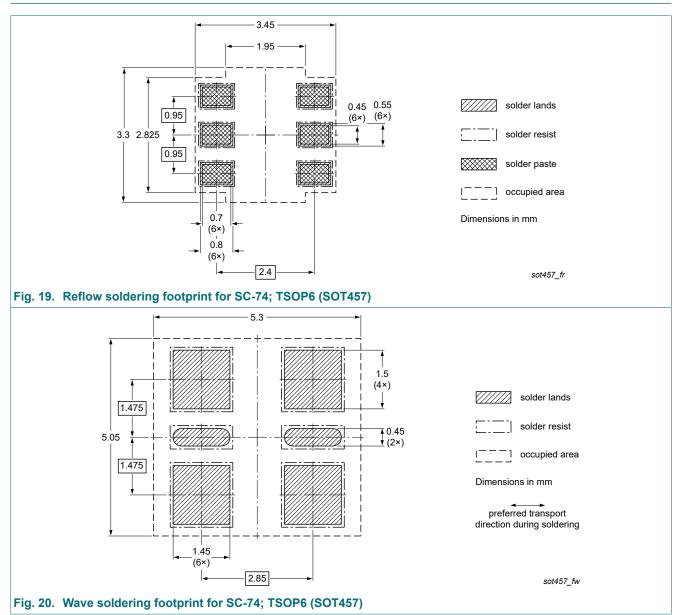
Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



13. Soldering



14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PMN48XPA2 v.1	20200420	Product data sheet	-	-		

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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